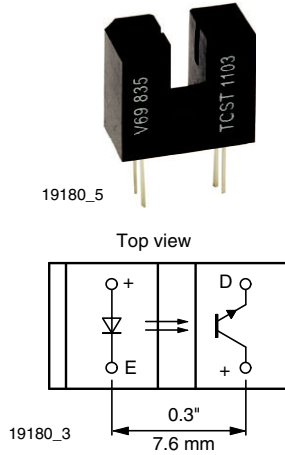


# Transmissive Optical Sensor with Phototransistor Output



## FEATURES

- Package type: leaded
- Detector type: phototransistor
- Dimensions (L x W x H in mm): 11.9 x 6.3 x 10.8
- Gap (in mm): 3.1
- Typical output current under test:  $I_C = 4$  mA (TCST1103)
- Typical output current under test:  $I_C = 2$  mA (TCST1202)
- Typical output current under test:  $I_C = 0.5$  mA (TCST1300)
- Daylight blocking filter
- Emitter wavelength: 950 nm
- Lead (Pb)-free soldering released
- Compliant to RoHS Directive 2002/95/EC and in accordance to WEEE 2002/96/EC


**RoHS**  
COMPLIANT

## DESCRIPTION

The TCST1103, TCST1202, and TCST1300 are transmissive sensors that include an infrared emitter and phototransistor, located face-to-face on the optical axes in a leaded package which blocks visible light. These part numbers include options for aperture width.

## APPLICATIONS

- Optical switch
- Photo interrupter
- Counter
- Encoder

PRODUCT SUMMARY				
PART NUMBER	GAP WIDTH (mm)	APERTURE WIDTH (mm)	TYPICAL OUTPUT CURRENT UNDER TEST <sup>(1)</sup> (mA)	DAYLIGHT BLOCKING FILTER INTEGRATED
TCST1103	3.1	1	4	Yes
TCST1202	3.1	0.5	2	Yes
TCST1300	3.1	0.25	0.5	Yes

### Note

- Conditions like in table basic characteristics/coupler

ORDERING INFORMATION			
ORDERING CODE	PACKAGING	VOLUME <sup>(1)</sup>	REMARKS
TCST1103	Tube	MOQ: 1020 pcs, 85 pcs/tube	Without mounting flange
TCST1202	Tube	MOQ: 1020 pcs, 85 pcs/tube	Without mounting flange
TCST1300	Tube	MOQ: 1020 pcs, 85 pcs/tube	Without mounting flange

### Note

- MOQ: minimum order quantity

ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25$ °C, unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>COUPLER</b>				
Total power dissipation	$T_{amb} \leq 25$ °C	$P_{tot}$	250	mW
Ambient temperature range		$T_{amb}$	- 55 to + 85	°C
Storage temperature range		$T_{stg}$	- 55 to + 100	°C
Soldering temperature	Distance to package: 2 mm; $t \leq 5$ s	$T_{sd}$	260	°C



ABSOLUTE MAXIMUM RATINGS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)				
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
<b>INPUT (EMITTER)</b>				
Reverse voltage		$V_R$	6	V
Forward current		$I_F$	60	mA
Forward surge current	$t_p \leq 10\text{ }\mu\text{s}$	$I_{FSM}$	3	A
Power dissipation	$T_{amb} \leq 25\text{ }^{\circ}\text{C}$	$P_V$	100	mW
Junction temperature		$T_j$	100	$^{\circ}\text{C}$
<b>OUTPUT (DETECTOR)</b>				
Collector emitter voltage		$V_{CEO}$	70	V
Emitter collector voltage		$V_{ECO}$	7	V
Collector peak current	$t_p/T = 0.5, t_p \leq 10\text{ ms}$	$I_{CM}$	200	mA
Power dissipation	$T_{amb} \leq 25\text{ }^{\circ}\text{C}$	$P_V$	150	mW
Junction temperature		$T_j$	100	$^{\circ}\text{C}$

**ABSOLUTE MAXIMUM RATINGS**

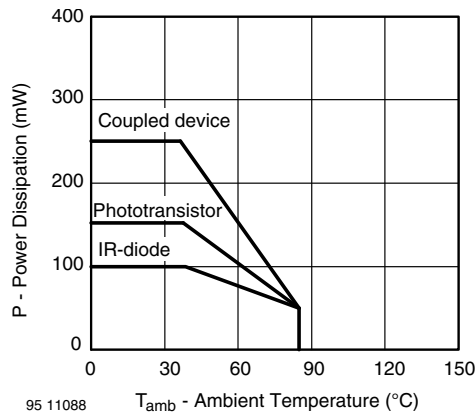


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

BASIC CHARACTERISTICS ( $T_{amb} = 25\text{ }^{\circ}\text{C}$ , unless otherwise specified)							
PARAMETER	TEST CONDITION	PART	SYMBOL	MIN.	TYP.	MAX.	UNIT
<b>COUPLER</b>							
Current transfer ratio	$V_{CE} = 5\text{ V}, I_F = 20\text{ mA}$	TCST1103	CTR	10	20		%
		TCST1202	CTR	5	10		%
		TCST1300	CTR	1.25	2.5		%
Collector current	$V_{CE} = 5\text{ V}, I_F = 20\text{ mA}$	TCST1103	$I_C$	2	4		mA
		TCST1202	$I_C$	1	2		mA
		TCST1300	$I_C$	0.25	0.5		mA
Collector emitter saturation voltage	$I_F = 20\text{ mA}, I_C = 1\text{ mA}$	TCST1103	$V_{CEsat}$			0.4	V
	$I_F = 20\text{ mA}, I_C = 0.5\text{ mA}$	TCST1202	$V_{CEsat}$			0.4	V
	$I_F = 20\text{ mA}, I_C = 0.1\text{ mA}$	TCST1300	$V_{CEsat}$			0.4	V
Resolution, path of the shutter crossing the radiant sensitive zone	$I_{Crel} = 10\text{ \% to }90\text{ \%}$	TCST1103	s		0.6		mm
		TCST1202	s		0.4		mm
		TCST1300	s		0.2		mm